

isc N-Channel MOSFET Transistor

2SK1199

DESCRIPTION

- Drain Current –I_D= 2A@ T_C=25 °C
- · Drain Source Voltage-
 - : V_{DSS}= 900V(Min)
- · Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

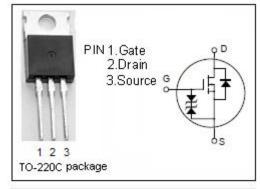
 Designed for high voltage, high speed power switching applications such as switching regulators, converters, solenoid and relay drivers.

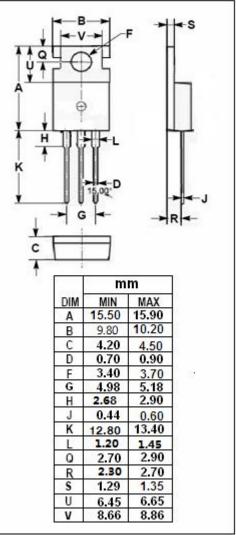
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	ARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage (V _{GS} =0)	900	V
V _{GS}	Gate-Source Voltage	±20	V
I _D	Drain Current-continuous@ TC=25℃	2	Α
P _{tot}	Total Dissipation@TC=25℃	50	W
Tj	Max. Operating Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$



SYMBOL	PARAMETER	MAX	UNIT
Rth j-c	Thermal Resistance,Junction to Case	0.83	°C/W
R _{th j-a}	Thermal Resistance,Junction to Ambient	35	°C/W







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• ELECTRICAL CHARACTERISTICS (Tc=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0; I _D = 10mA	900			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =10 V _{GS} ; I _D =1mA	2.0		4.0	V
R _{DS(on)}	Drain-Source On-stage Resistance	V _{GS} =10V; I _D = 5A		5.0	7.0	Ω
I _{GSS}	Gate Source Leakage Current	V _{GS} = ±16V;V _{DS} = 0			±10	uA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =720V; V _{GS} = 0			250	uA
V _{SD}	Diode Forward Voltage	I _F =2A; V _{GS} =0		0.9		V
tr	Rise time			60		ns
ton	Turn-on time	V_{GS} =10V; I_D =1A; R_L =30 Ω		70		ns
tf	Fall time			60		ns
toff	Turn-off time			125		ns

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